TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

2SC3710A

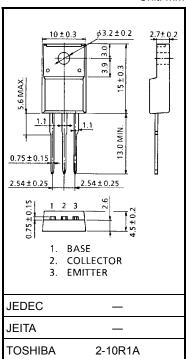
High-Current Switching Applications

• Low collector saturation voltage: VCE (sat) = 0.4 V (max)

- High-speed switching: $t_{stg} = 1.0 \ \mu s$ (typ.)
- Complementary to 2SA1452A

Maximum Ratings (Tc = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	80	V
Collector-emitter voltage	V _{CEO}	80	V
Emitter-base voltage	V _{EBO}	6	V
Collector current	Ι _C	12	А
Base current	Ι _Β	2	A
Collector power dissipation (Tc = 25°C)	Pc	30	W
Junction temperature	Тј	150	°C
Storage temperature range	T _{stg}	-55 to 150	°C



Electrical Characteristics (Tc = 25°C)

Weight: 1.7 g (typ.)

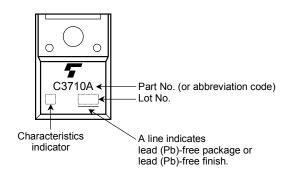
Chara	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off c	urrent	I _{CBO}	V _{CB} = 80 V, I _E = 0	_	_	10	μA
Emitter cut-off cur	rent	I _{EBO}	V _{EB} = 6 V, I _C = 0		_	10	μA
Collector-emitter b	oreakdown voltage	V (BR) CEO	I _C = 50 mA, I _B = 0	80	_	_	V
DC current gain		h _{FE (1)} (Note)	V _{CE} = 1 V, I _C = 1 A	70	_	240	
		h _{FE (2)}	V _{CE} = 1 V, I _C = 6 A	40	_	—	
Collector-emitter s	aturation voltage	V _{CE (sat)}	I _C = 6 A, I _B = 0.3 A	_	0.2	0.4	V
Base-emitter satu	ration voltage	V _{BE (sat)}	I _C = 6 A, I _B = 0.3 A	_	0.9	1.2	V
Transition frequen	су	f _T	V _{CE} = 5 V, I _C = 1 A		80	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz		220	_	pF
Switching time	Turn-on time	t _{on}	$ \begin{array}{c} 20 \ \mu s \\ \underline{m} \\ \underline{m}$	_	0.2	_	
	Storage time	t _{stg}			1.0	_	μs
	Fall time	t _f		_	0.2	_	

Note: hFE (1) classification O: 70 to 140, Y: 120 to 240

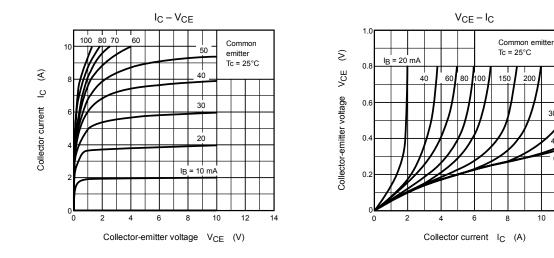
Unit: mm

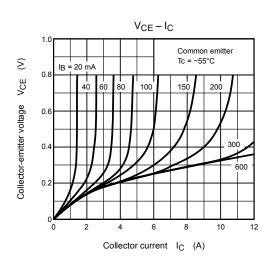
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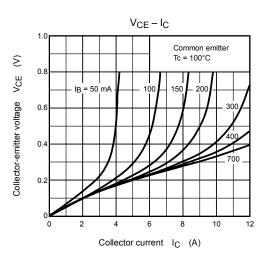
Marking

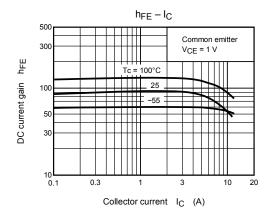


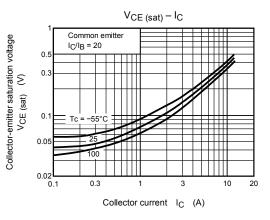
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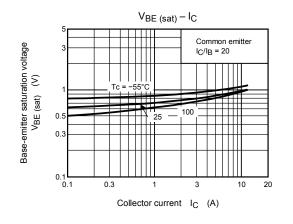


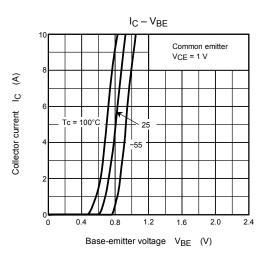


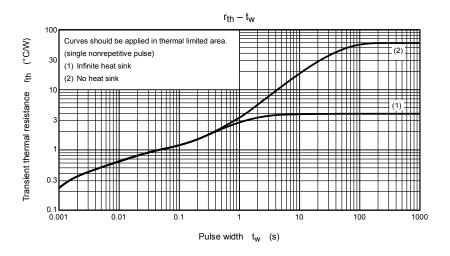


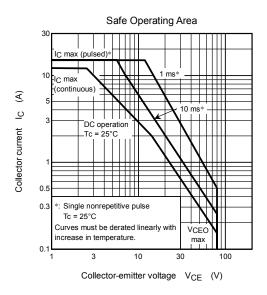


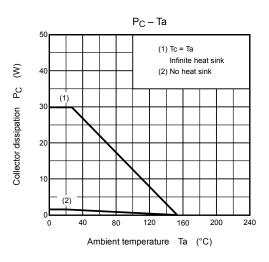
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